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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO	
09/412,328	10/05/1999	YUICHI SATO	204552016500	9541	
25227	7590 04-03-2003				
MORRISON & FOERSTER LLP			EXAMINER		
SUITE 300	IS BOULEVARD		WILLE, DO	WILLE, DOUGLAS A	
MCLEAN, VA 22102			ART UNIT	PAPER NUMBER	
			2814		
			DATE MAILED: 04/03/2003	DATE MAILED: 04/03/2003	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)				
	09/412,328	SATO, YUICHI				
Office Action Summary	Examiner	Art Unit				
	Douglas A Wille	2814				
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply						
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply - If NO period for reply is specified above, the maximum statutory period w - Failure to reply within the set or extended period for reply will, by statute, - Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).  Status	6(a). In no event, however, may within the statutory minimum of till apply and will expire SIX (6) M cause the application to become	a reply be timely filed  hirty (30) days will be considered timely.  ONTHS from the mailing date of this communication  ABANDONED (35 U.S.C. § 133)				
1) Responsive to communication(s) filed on <u>04 F</u>	ebruary 200 <u>3</u> .					
2a) ☐ This action is <b>FINAL</b> . 2b) ☑ Thi	s action is non-final.					
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.  Disposition of Claims						
4) Claim(s) 2,3,5-7 and 9 is/are pending in the application.						
4a) Of the above claim(s) is/are withdrawn from consideration.						
5) Claim(s) is/are allowed.						
6)						
7) Claim(s) is/are objected to.						
8) Claim(s) are subject to restriction and/or election requirement.						
Application Papers						
9)☐ The specification is objected to by the Examiner.						
10)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.						
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1 85(a)						
11) The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner						
If approved, corrected drawings are required in reply to this Office action.						
12) The oath or declaration is objected to by the Examiner.						
Priority under 35 U.S.C. §§ 119 and 120						
13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).						
a) All b) Some * c) None of:						
1. Certified copies of the priority documents have been received.						
2. Certified copies of the priority documents have been received in Application No						
<ul> <li>3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).</li> <li>* See the attached detailed Office action for a list of the certified copies not received.</li> </ul>						
14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).						
a) ☐ The translation of the foreign language provisional application has been received. 15)☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.						
Attachment(s)						
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice	w Summary (PTO-413) Paper No(s) of Informal Patent Application (PTO-152)				
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#### **DETAILED ACTION**

## Claim Rejections - 35 USC § 103

1. Claims 2 and 7 are rejected under 35 U.S.C. 103(a) as being unpatentable over Applicant's admitted prior art and Hu et al.

- 2. With respect to claim 2, Applicant's admitted prior art, Figure 9, shows and SRAM comprised of CMOS devices. Hu et al. show a DTMOS device (see Figure 7 and column 1, line 8 et seq.) that has the n-well deeper than the p-well and that can be used in CMOS circuitry for the advantages shown (column 2, line 46). Hu et al. show that the p-well is in the n-well and is shallower and that a trench 38 is deeper than the shallow well and shallower than the deep well. It would have been obvious to modify the basic device to include the DTMOS device shown by Hu et al. for the advantages shown. Note that the gates of the devices are connected to a power supply and therefore, so are the channel forming regions.
- 3. With respect to claim 7, it would be obvious to use these transistors for any purpose
- 4. Claim 3 is rejected under 35 U.S.C. 103(a) as being unpatentable over Applicant's admitted prior art and Hu et al. and further in view of Tsui et al.
- 5. Tsui et al. show the use of dual thickness gate oxides with thinner gate oxides used for low voltage devices (column 1, line 14). Since DTMOS devices use lower voltages it would have been obvious to use thinner oxides for the lower voltage devices and to use normal gate oxides for other devices.
- 6. Claims 5, 6 and 9 are rejected under 35 U.S.C. 103(a) as being unpatentable over Applicant's admitted prior art and Hu et al. and further in view of Hodges et al.

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7. Hodges et al. shows the formation of peripheral circuits for a memory device that use MOS structures (see page 368 and 369) and it would be obvious to use the DTMOS devices for these structures for the advantages shown.

## Response to Arguments

- 8. Applicant's arguments filed 2/4/03 have been fully considered but they are not persuasive.
- 9. Comments directed to the amended claims are addressed in the rejection above.
- 10. With respect to claim 9, Applicant states that the prior art quoted does not show the use of the transistors but note that since the claims are drawn to a device the function carries no weight. Applicant also states that there is no motivation for combining the references but note that since the secondary reference shows an improvement of a device the improvement would be applicable to any device and the justification is to improve the function.

#### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Douglas A Wille whose telephone number is (703) 308-4949. The examiner can normally be reached on M-F (6:15-3:45).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael Fahmy can be reached on (703) 308-4918. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 308-7722 for regular communications and (703) 308-7722 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

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